

NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 12. See TN3019A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CEO}	Collector-Emitter Voltage	45	V	
V _{CES}	Collector-Base Voltage	50	V	
V _{EBO}	Emitter-Base Voltage	5.0	V	
Ic	Collector Current - Continuous	1.0	А	
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

Symbol	Characteristic	Мах	Units	
		BC337-16 / BC337-25		
P _D	Total Device Dissipation	625	mW	
	Derate above 25°C	5.0	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
R _{θJA}	Thermal Resistance, Junction to Ambient	200	°C/W	

Electr	ical Characteristics TA =	= 25°C unless otherwise noted			
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	45		V
V _{(BR)CES}	Collector-Base Breakdown Voltage	$I_{C} = 100 \ \mu A, \ I_{E} = 0$	50		V
	Enducer Development development	$I_{E} = 100 \ \mu A, I_{C} = 0$	5.0		V
	Emitter-Base Breakdown Voltage	$E = 100 \mu R, R = 0$			
V _{(BR)EBO} I _{CBO}	Collector Cutoff Current	$ \begin{array}{l} V_{CB} = 20 \ V, \ I_{E} = 0, \ T_{A} = +25 \ ^{\circ}\text{C} \\ V_{CB} = 20 \ V, \ I_{E} = 0, \ T_{A} = +150 \\ ^{\circ}\text{C} \end{array} $		100 5.0	nA μA

ON

h _{FE}	DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 100 \text{ mA}$			
		337-16	100	250	
		337-25	160	400	
		$V_{CE} = 1.0 \text{ V}, I_{C} = 500 \text{ mA}$	40		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		0.7	V
V _{BE(on)}	Base-Emitter On Voltage	$V_{CE} = 1.0 \text{ V}, I_{C} = 500 \text{ mA}$		1.2	V

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